

Figure 2. Simplified Block Diagram

Table 1. PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	V _{in}	Positive Power Supply Input.
2	GND	Power Supply Ground; Device Substrate.
3	V _{out}	Regulated Output Voltage.
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Table 2. ABSOLUTE MAXIMUM RATINGS (Note 1)

Rating	Rating			Unit
Input Voltage Range	(for V _{out} : 5.0 – 15 V)	V _{in}	-0.3 to 35	V
Power Dissipation		P_{D}	Internally Limited	W
Maximum Junction Temperature	T _{J(max)}	150	°C	
Storage Temperature Range	T _{stg}	−65 to +150	°C	
ESD Capability, Human Body Model (Note 2)	NCP7805, NCP7808 NCP7812, NCP7815	ESD _{HBM}	4 3	kV
ESD Capability, Machine Model (Note 2)	ESD _{MM}	400	V	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Refer to ELÉCTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per EIA/JESD22-A114

ESD Machine Model tested per EIA/JESD22-A115

Latchup Current Maximum Rating: ≤150 mA per JEDEC standard: JESD78

Table 3. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, TO-220-3 (Note 3) Thermal Resistance, Junction-to-Case Thermal Resistance, Junction-to-Air (Note 4)	R _θ JC R _θ JA	7.5 65	°C/W

- 3. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area
- 4. Value based on thermal measurement in a test socket.

Table 4. OPERATING RANGES (Note 5)

	Rating	Symbol	Min	Max	Unit
Input Voltage (Note 6)	(for V _o	_{ut} : 5.0 – 15 V) V _{in}	7.0	35	V
Junction Temperature		T _J	0	125	°C

- 5. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- 6. Minimum V_{in} = 7.0 V or $(V_{out} + V_{DO})$, whichever is higher.

Table 5. ELECTRICAL CHARACTERISTICS (V_{in} = 10 V, I_{O} = 500 mA, T_{J} = 0°C to 125°C, unless otherwise noted) (Note 7)

			NCP7805		
Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = 25°C)	Vo	4.8	5.0	5.2	Vdc
Output Voltage (5.0 mA \leq I _O \leq 1.0 A, P _D \leq 15 W) 7.0 Vdc \leq V _{in} \leq 20 Vdc	Vo	4.75	5.0	5.25	Vdc
ine Regulation ($T_J = 25^{\circ}C$) 7.5 Vdc $\leq V_{in} \leq 20$ Vdc 8.0 Vdc $\leq V_{in} \leq 12$ Vdc	Reg _{line}	- -	1.1 0.6	100 50	mV
.oad Regulation (T_J = 25°C) 5.0 mA \leq I $_O$ \leq 1.0 A 5.0 mA \leq I $_O$ \leq 1.5 A	Reg _{load}		1.5 2.9	50 100	mV
Quiescent Current (T _J = 25°C)	I _B		3.0	8	mA
Quiescent Current Change 7.0 Vdc \leq V $_{in}$ \leq 25 Vdc 5.0 mA \leq I $_{O}$ \leq 1.0 A	Δl _B	-	0.28 0.07	1.3 0.5	mA
Ripple Rejection (Note 8) 8.0 $Vdc \le V_{in} \le 18 Vdc, f = 120 Hz$	RR	62	75	$O_{\zeta_{+}}$	dB
Oropout Voltage (I _O = 1.0 A, T _J = 25°C) (Note 8)	V _I – V _O	-	2.0	_	Vdc
Output Noise Voltage ($T_J = 25^{\circ}C$) (Note 8) 10 Hz $\leq f \leq$ 100 kHz	V _n		6.8	<i>P</i> -	μV/V _C
Output Resistance f = 1.0 kHz (Note 8)	r _O	V- (2.2	_	mΩ
Short Circuit Current Limit (T _J = 25°C) (Note 8) V _{in} = 35 Vdc	I _{SC}	MIL	0.3	-	А
Peak Output Current (T _J = 25°C) (Note 8)	I _{max}	- -0	2.4	-	Α
Average Temperature Coefficient of Output Voltage (Note 8)	TCVo	1-	0.13	-	mV/°C
Peak Output Current (T _J = 25°C) (Note 8) Average Temperature Coefficient of Output Voltage (Note 8) Performance guaranteed over the indicated operating temperature T _J = T _A = 25°C. Low duty cycle pulse techniques are used during testivalue based on design and/or characterization.	range by design a ng to maintain the	nd/or characte junction tempe	rization, prod rature as clos	uction tested e to ambient	l at as poss

Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
 Value based on design and/or characterization.

Table 6. ELECTRICAL CHARACTERISTICS (V_{in} = 14 V, I_{O} = 500 mA, T_{J} = 0°C to 125°C, unless otherwise noted) (Note 9)

			NCP7808		
Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = 25°C)	Vo	7.68	8.0	8.32	Vdc
Output Voltage (5.0 mA \leq I _O \leq 1.0 A, P _D \leq 15 W) 10.5 Vdc \leq V _{in} \leq 23 Vdc	Vo	7.60	8.0	8.40	Vdc
Line Regulation ($T_J = 25^{\circ}C$) 10.5 Vdc $\leq V_{in} \leq 25$ Vdc 11.0 Vdc $\leq V_{in} \leq 17$ Vdc	Reg _{line}	- -	1.8 1.0	160 80	mV
Load Regulation ($T_J = 25^{\circ}C$) 5.0 mA $\leq I_O \leq$ 1.5 A	Reg _{load}	-	3.7	160	mV
Quiescent Current (T _J = 25°C)	I _B	_	3.0	8.0	mA
Quiescent Current Change 10.5 Vdc \leq V _{in} \leq 25 Vdc 5.0 mA \leq I _O \leq 1.0 A	Δl _B	-	- -	1.0 0.5	mA
Ripple Rejection (Note 10) 11.5 $Vdc \le V_{in} \le 21.5 Vdc$, f = 120 Hz	RR	56	72	·90.	dB
Dropout Voltage (I _O = 1.0 A, T _J = 25°C) (Note 10)	$V_l - V_O$	_	2.0	-	Vdc
Output Noise Voltage ($T_J = 25^{\circ}C$) (Note 10) 10 Hz \leq f \leq 100 kHz	Vn	-	6.8	~ -	μV/V _O
Output Resistance f = 1.0 kHz (Note 10)	r _O		2.7) -	mΩ
Short Circuit Current Limit (T _J = 25°C) (Note 10) V _{in} = 35 Vdc	I _{SC}	\\\C\	0.3	-	А
Peak Output Current (T _J = 25°C) (Note 10)	I _{max}		2.4	_	Α
Average Temperature Coefficient of Output Voltage (Note 10)	TCV _O	2,O	0.24	-	mV/°C

Average Temperature Coefficient of Output Voltage (Note 10)

TCVO

0.24

mV/°C

Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 10. Value based on design and/or characterization.

Table 7. ELECTRICAL CHARACTERISTICS (V_{in} = 19 V, I_{O} = 500 mA, T_{J} = 0°C to 125°C, unless otherwise noted) (Note 11)

			NCP7812		
Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = 25°C)	Vo	11.52	12	12.48	Vdc
Output Voltage (5.0 mA \leq I _O \leq 1.0 A, P _D \leq 15 W) 14.5 Vdc \leq V _{in} \leq 27 Vdc	Vo	11.40	12	12.60	Vdc
Line Regulation ($T_J = 25^{\circ}C$) 14.5 Vdc $\leq V_{in} \leq 30$ Vdc 16 Vdc $\leq V_{in} \leq 22$ Vdc	Reg _{line}	- -	2.7 1.4	240 120	mV
Load Regulation ($T_J = 25^{\circ}C$) 5.0 mA $\leq I_O \leq$ 1.5 A	Reg _{load}	-	5.5	240	mV
Quiescent Current (T _J = 25°C)	I _B	_	3.0	8.0	mA
Quiescent Current Change 14.5 Vdc \leq V _{in} \leq 30 Vdc 5.0 mA \leq I _O \leq 1.0 A	ΔI_{B}	-	- -	1.0 0.5	mA
Ripple Rejection (Note 12) 15 Vdc ≤ V _{in} ≤ 25 Vdc, f = 120 Hz	RR	55	71	· 00-	dB
Dropout Voltage (I _O = 1.0 A, T _J = 25°C) (Note 12)	V _I – V _O	_	2.0	-	Vdc
Output Noise Voltage ($T_J = 25^{\circ}C$) (Note 12) 10 Hz \leq f \leq 100 kHz	Vn	-	6,8	~ -	μV/V _O
Output Resistance f = 1.0 kHz (Note 12)	r _O	11-	3.6) -	mΩ
Short Circuit Current Limit (T _J = 25°C) (Note 12) V _{in} = 35 Vdc	I _{SC}	\\\C\	0.3	-	А
Peak Output Current (T _J = 25°C) (Note 12)	I _{max}		2.4	-	Α
Average Temperature Coefficient of Output Voltage (Note 12)	TCV _O	2,O	0.47	-	mV/°C

Average Temperature Coefficient of Output Voltage (Note 12)

TCVO - 0.47 - mV/°C

11. Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 12. Value based on design and/or characterization.

Table 8. ELECTRICAL CHARACTERISTICS (V_{in} = 23 V, I_{O} = 500 mA, T_{J} = 0°C to 125°C, unless otherwise noted) (Note 13)

			NCP7815		
Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = 25°C)	Vo	14.40	15	15.60	Vdc
Output Voltage (5.0 mA \leq I $_{O}$ \leq 1.0 A, P $_{D}$ \leq 15 W) 17.5 Vdc \leq V $_{in}$ \leq 30 Vdc	Vo	14.25	15	15.75	Vdc
Line Regulation ($T_J = 25^{\circ}C$) 17.9 Vdc $\leq V_{in} \leq 30$ Vdc 20 Vdc $\leq V_{in} \leq 26$ Vdc	Reg _{line}	- -	3.3 1.8	300 150	mV
Load Regulation (T _J = 25°C) 5.0 mA \leq I _O \leq 1.5 A	Reg _{load}	-	6.9	300	mV
Quiescent Current (T _J = 25°C)	Ι _Β	_	3.0	8.0	mA
Quiescent Current Change 17.5 Vdc \leq V _{in} \leq 30 Vdc 5.0 mA \leq I _O \leq 1.0 A	ΔI_{B}	-	- -	1.0 0.5	mA
Ripple Rejection (Note 14) $18.5 \text{ Vdc} \le V_{in} \le 28.5 \text{ Vdc}, f = 120 \text{ Hz}$	RR	54	70	.08	dB
Dropout Voltage (I _O = 1.0 A, T _J = 25°C) (Note 14)	V _I – V _O	_	2.0	-	Vdc
Output Noise Voltage ($T_J = 25$ °C) (Note 14) 10 Hz \leq f \leq 100 kHz	Vn	-	6.8	<u>-</u>	μV/V _O
Output Resistance f = 1.0 kHz (Note 14)	r _O		4.7) -	mΩ
Short Circuit Current Limit (T _J = 25°C) (Note 14) V _{in} = 35 Vdc	I _{SC}	~\\C\	0.3	-	А
Peak Output Current (T _J = 25°C) (Note 14)	I _{max}		2.4	-	Α
Average Temperature Coefficient of Output Voltage (Note 14)	TCV _O	D' ZO	0.42	-	mV/°C

Average Temperature Coefficient of Output Voltage (Note 14)

13. Performance guaranteed over the indicated operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible. 14. Value based on design and/or characterization.

TYPICAL CHARACTERISTICS

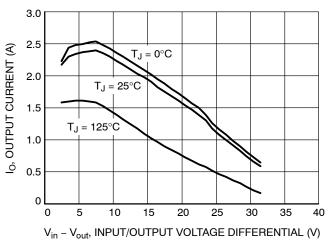


Figure 3. Peak Output Current as a Function of Input/Output Differential Voltage (NCP7805)

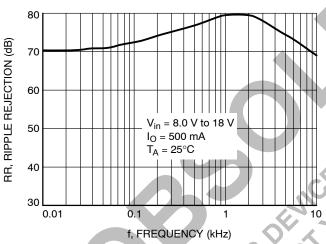


Figure 5. Ripple Rejection as a Function of Frequency (NCP7805)

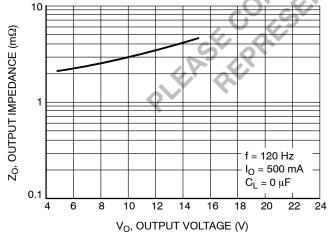


Figure 7. Output Impedance as a Function of Output Voltage

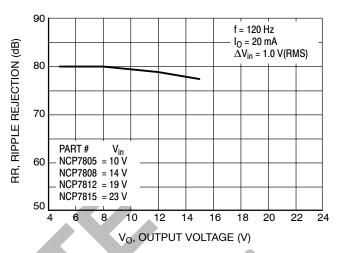


Figure 4. Ripple Rejection as a Function of Output Voltage

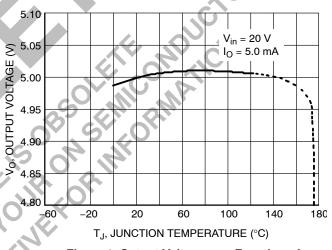


Figure 6. Output Voltage as a Function of Junction Temperature (NCP7805)

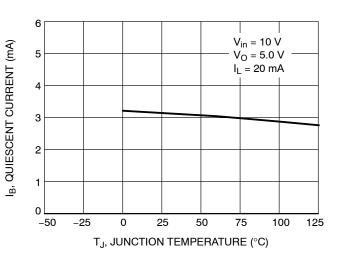


Figure 8. Quiescent Current as a Function of Temperature (NCP7805)

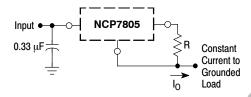
APPLICATIONS INFORMATION

Design Considerations

The NCP7800 Series of fixed voltage regulators are designed with Thermal Overload Protection that shuts down the circuit when subjected to an excessive power overload condition, Internal Short Circuit Protection that limits the maximum current the circuit will pass, and Output Transistor Safe–Area Compensation that reduces the output short circuit current as the voltage across the pass transistor is increased.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. An

input bypass capacitor should be selected to provide good high–frequency characteristics to insure stable operation under all load conditions. A 0.33 μF or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulators input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead.



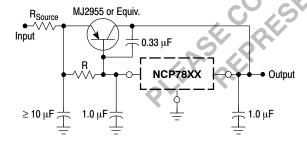
The NCP7800 regulators can also be used as a current source when connected as above. In order to minimize dissipation the NCP7805 is chosen in this application. Resistor R determines the current as follows:

$$I_0 = \frac{5.0 \text{ V}}{R} + I_B$$

 $I_B \cong 3.2$ mA over line and load changes.

For example, a 1.0 A current source would require R to be a 5.0 Ω , 10 W resistor and the output voltage compliance would be the input voltage less 7.0 V.

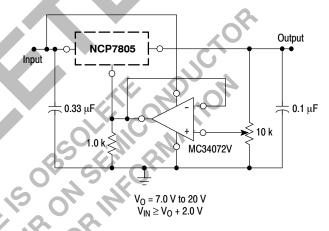
Figure 9. Current Regulator



XX = 2 digits of type number indicating voltage.

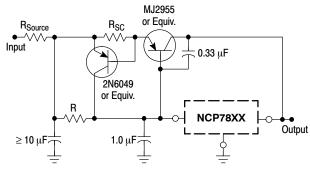
The NCP7800 series can be current boosted with a PNP transistor. The MJ2955 provides current to 5.0 A. Resistor R in conjunction with the V_{BE} of the PNP determines when the pass transistor begins conducting; this circuit is not short circuit proof. Input/output differential voltage minimum is increased by V_{BE} of the pass transistor.

Figure 11. Current Boost Regulator



The addition of an operational amplifier allows adjustment to higher or intermediate values while retaining regulation characteristics. The minimum voltage obtainable with this arrangement is 2.0 V greater than the regulator voltage.

Figure 10. Adjustable Output Regulator



XX = 2 digits of type number indicating voltage.

The circuit of Figure 11 can be modified to provide supply protection against short circuits by adding a short circuit sense resistor, R_{SC} , and an additional PNP transistor. The current sensing PNP must be able to handle the short circuit current of the three-terminal regulator. Therefore, a four-ampere plastic power transistor is specified.

Figure 12. Short Circuit Protection

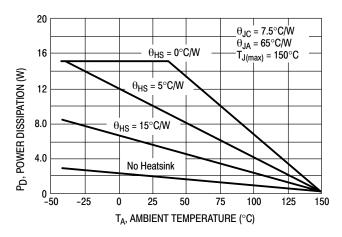


Figure 13. Worst Case Power Dissipation vs. Ambient Temperature (TO-220)

Protection Diode

The NCP7800 Series has internal low impedance (about $1\,\Omega$) diode path that normally does not require protection when used in the typical regulator applications. The path connects between output and input and it can withstand a peak surge current of about 5 A for a reasonable time (several milliseconds). Normal cycling of Vin cannot generate a current surge of this magnitude for too long time since output capacitor discharges from output to input and follows input voltage therefore the magnitude of reverse current is not so high. However, when Vin is shorted or crowbarred to ground and output cap is too large and moreover if higher voltage option is used then the peak of reverse current is much higher than 5 A and lasts more than

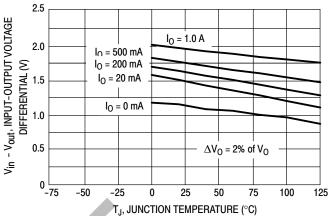


Figure 14. Input Output Differential as a Function of Junction Temperature

several milliseconds. In this case a damage may occur to the regulator.

To protect the regulator the external bypass diode connected between output and input is recommended. The protection diode should be rated for sufficient peak current.

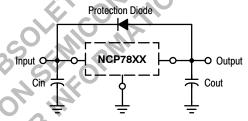


Figure 15. Protection Diode Placement

DEFINITIONS

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Maximum Power Dissipation – The maximum total device dissipation for which the regulator will operate within specifications.

Quiescent Current – That part of the input current that is not delivered to the load.

Output Noise Voltage – The rms ac voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

Long Term Stability – Output voltage stability under accelerated life test conditions with the maximum rated voltage listed in the devices' electrical characteristics and maximum power dissipation.

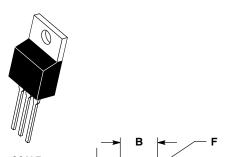
ORDERING INFORMATION

Device	Nominal Voltage	Operating Temperature Range	Package	Shipping
NCP7805TG	5.0 V	T _J = 0°C to +125°C	TO-220 (Pb-Free)	50 Units / Rail
NCP7808TG	8.0 V	T _J = 0°C to +125°C	TO-220 (Pb-Free)	50 Units / Rail
NCP7812TG	12 V	T _J = 0°C to +125°C	TO-220 (Pb-Free)	50 Units / Rail
NCP7815TG	15 V	T _J = 0°C to +125°C	TO-220 (Pb-Free)	50 Units / Rail
	PIERSE PR	T _J = 0°C to +125°C	A A A A A A A A A A A A A A A A A A A	

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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TO-220, SINGLE GAUGE CASE 221AB-01 **ISSUE A**

DATE 16 NOV 2010

- NOTES:

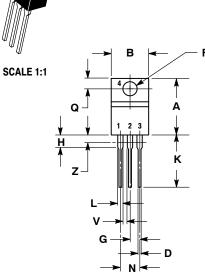
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

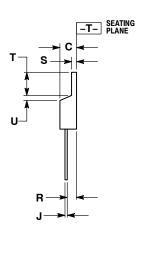
 2. CONTROLLING DIMENSION: INCHES.

 3. DIMENSION 2 DEFINES A ZONE WHERE ALL BODY AND LEAD INREGULARTIES ARE ALLOWED.

 4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS S = 0.045 0.055 INCHES (1.143 1.397 MM)

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04





STYLE 1:		STYLE 2:		STYLE 3:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE
2.	COLLECTOR	2.	EMITTER	2.	ANODE
3.	EMITTER	3.	COLLECTOR	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE
STYLE 5:		STYLE 6:		STYLE 7:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE
4.	DRAIN	4.	CATHODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:	
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN
2.	COLLECTOR	2.	SOURCE	2.	SOURCE
3.	EMITTER	3.	DRAIN	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE

3.	MAIN TERMINAL 1 MAIN TERMINAL 2 GATE MAIN TERMINAL 2
2. 3.	CATHODE ANODE EXTERNAL TRIP/DELAY ANODE

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DESCRIPTION:	TO-220, SINGLE GAUGE	•	PAGE 1 OF 1

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